APPLN. FILING DATE: OCTOBER 3, 3005
TITLE: INSULATED POWER SEMICONDUCTOR
MODULE WITH REDUCED PARTIAL DISCHARGE AND
MANUFACTURING METHOD
INVENTOR(S): AMINA HAMIDI
ATTY. DKT. No.: 004501-820 SHEET 1 OF 7

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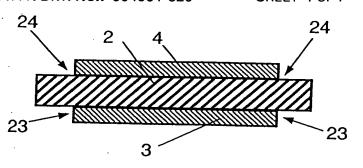


Fig. 1a

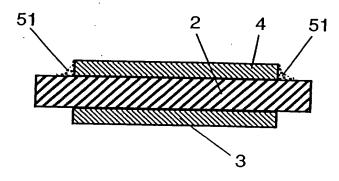


Fig. 1b

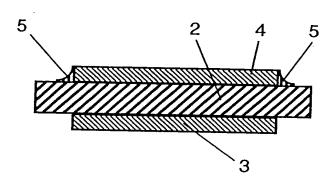


Fig. 1c

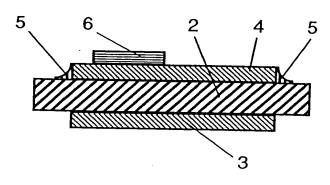
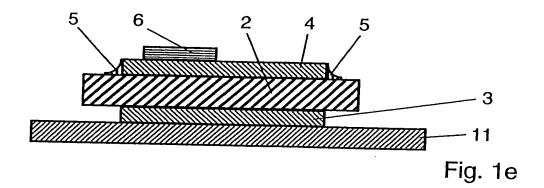
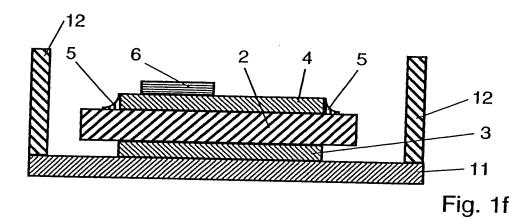


Fig. 1d

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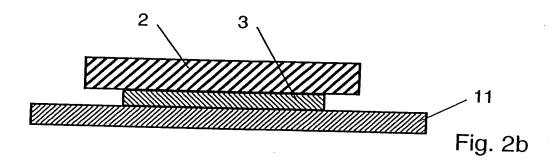


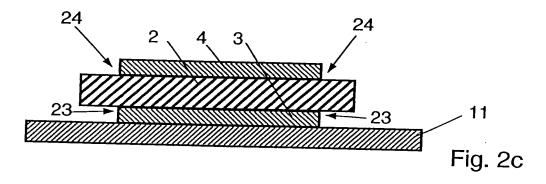


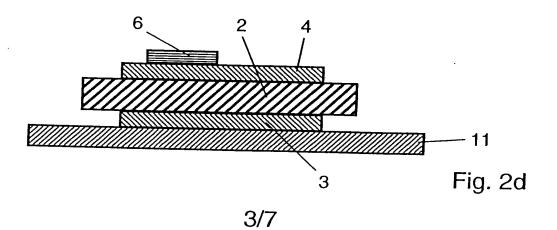
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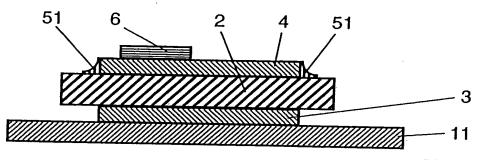


Fig. 2e

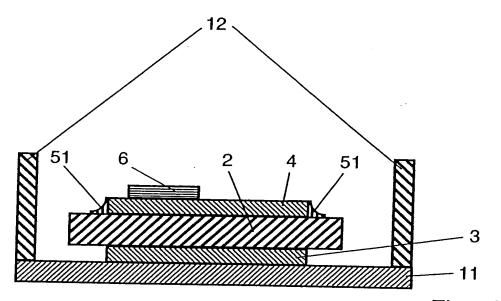
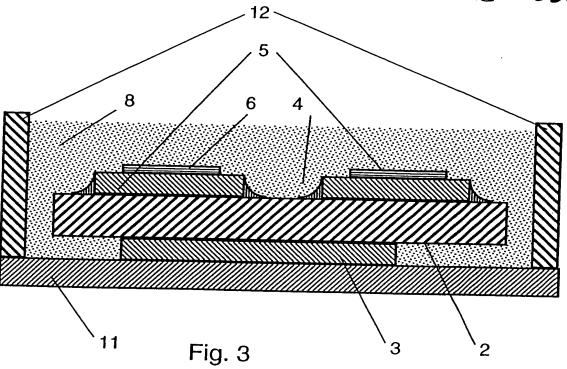
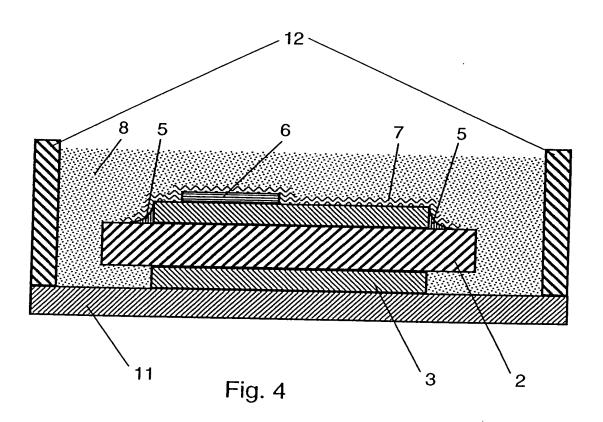


Fig. 2f

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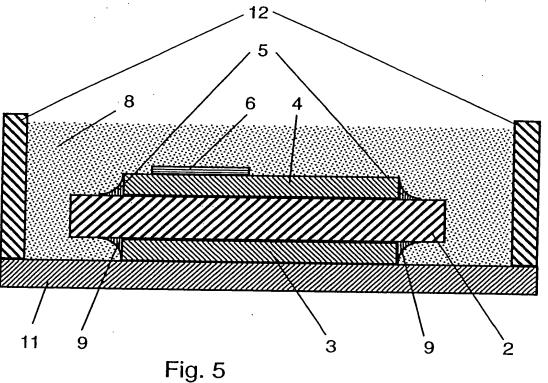




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